

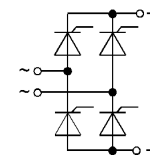
|                                     |  |                   |                   |                   |
|-------------------------------------|--|-------------------|-------------------|-------------------|
| $V_{DRM}$<br>$V_{RSM}$<br>$V_{RRM}$ | $I_D$ ( $T_{case} = 89\text{ °C}$ , full conduction)<br>28 A |                   |                   |                   |
| 400 V                               | –  | –                 | <b>SKBZ 28/04</b> | <b>SKCH 28/04</b> |
| 600 V                               | <b>SKBT 28/06</b>  | <b>SKBH 28/06</b> | <b>SKBZ 28/06</b> | <b>SKCH 28/06</b> |
| 800 V                               | <b>SKBT 28/08</b>  | <b>SKBH 28/08</b> | <b>SKBZ 28/08</b> | <b>SKCH 28/08</b> |
| 1200 V                              | <b>SKBT 28/12</b>  | <b>SKBH 28/12</b> | <b>SKBZ 28/12</b> | <b>SKCH 28/12</b> |
| 1400 V                              | <b>SKBT 28/14</b>  | <b>SKBH 28/14</b> | <b>SKBZ 28/14</b> | <b>SKCH 28/14</b> |

**SEMIPONT® 1**  
**Controllable Bridge Rectifiers**

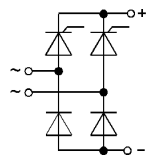
**SKBT 28**    **SKBZ 28**  
**SKBH 28**    **SKCH 28**



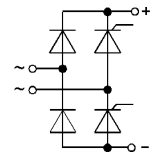
| Symbol                                 | Conditions  | SKBT 28<br>SKBH 28                                      | SKCH 28<br>SKBZ 28       |
|--|---|---|--------------------------|
| $I_D$                                  | $T_{case} = 85\text{ °C}$ , inductive load<br>$T_{amb} = 45\text{ °C}$ , chassis <sup>1)</sup><br>P5A/100<br>P13A/125<br>P1A/120              | 30 A<br>13 A<br>15 A<br>16 A<br>23 A                    |                          |
| $I_{TSM}, I_{FSM}$                     | $T_{vj} = 25\text{ °C}$ , 10 ms<br>$T_{vj} = 125\text{ °C}$ , 10 ms   | 320 A<br>280 A  |                          |
| $i^2t$                                 | $T_{vj} = 25\text{ °C}$ , 8,3...10 ms<br>$T_{vj} = 125\text{ °C}$ , 8,3...10 ms   | 510 A <sup>2</sup> s<br>390 A <sup>2</sup> s            |                          |
| $(di/dt)_{cr}$<br>$(dv/dt)_{cr}$       | $T_{vj} = 25\text{ °C}$ , 10 ms<br>$T_{vj} = 125\text{ °C}$ , $2/3 V_{DRM}$   | 50 A/ $\mu$ s<br>500 V/ $\mu$ s                         |                          |
| $I_H$<br>$I_L$                         | $T_{vj} = 25\text{ °C}$ , typ./max.<br>$T_{vj} = 25\text{ °C}$ , typ./max.  | 50 mA/150 mA<br>100 mA/300 mA                           |                          |
| $V_T$<br>$V_{T(TO)}$<br>$r_T$          | $T_{vj} = 25\text{ °C}$ ; $I_T = 75\text{ A}$<br>$T_{vj} = 125\text{ °C}$<br>$T_{vj} = 125\text{ °C}$   | 2,25 V<br>1,0 V<br>16 m $\Omega$                        |                          |
| $I_D$                                  | $T_{vj} = 125\text{ °C}$ ; $V_{DRM}$ , $V_{RRM}$  | 8 mA  |                          |
| $V_{GT}$<br>$I_{GT}$<br>$V_{GD}$       | $T_{vj} = 25\text{ °C}$ ; $V_D = 6\text{ V}$<br>$T_{vj} = 25\text{ °C}$ ; $V_D = 6\text{ V}$<br>$T_{vj} = 125\text{ °C}$ ; $V_D = 6\text{ V}$ | 2 V<br>100 mA<br>0,25 V                                 |                          |
| $R_{thjc}$<br>$R_{thch}$<br>$R_{thja}$ | per thyristor/diode<br>total<br>total   | 1,8 °C/W<br>0,45 °C/W<br>0,1 °C/W                       |                          |
| $T_{vj}$ , $T_{stg}$                   |   | 15 °C/W   |                          |
| $V_{isol}$<br>$M_1$<br>$w$             | a.c. 50...60 Hz; r.m.s.; 1 s / 1 min<br>case to heatsink; SI units/US units   | 3600 V~ / 3000 V~<br>2 Nm/18 lb. in. $\pm$ 15 %<br>66 g |                          |
| Case                                   |   | SKBT: G 22<br>SKBH: G 23                                | SKBZ: G 24<br>SKCH: G 25 |



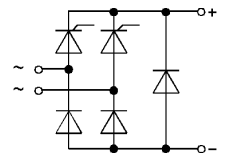
**SKBT**



**SKBH**



**SKBZ**



**SKCH**

**Features**

- Sturdy isolated metal baseplate
- Fast-on terminals with solder tips
- Suitable for wave soldering
- High surge current rating
- UL recognized, file no. E 63 532

**Typical Applications**

- Controllable single-phase rectifiers
- DC power supplies
- DC motor controllers
- DC motor field controllers

<sup>1)</sup> Painted metal sheet of minimum 250 x 250 x 1 mm<sup>3</sup>:  $R_{thca} = 1,85\text{ °C/W}$

<sup>2)</sup> Freely suspended or mounted on an insulator

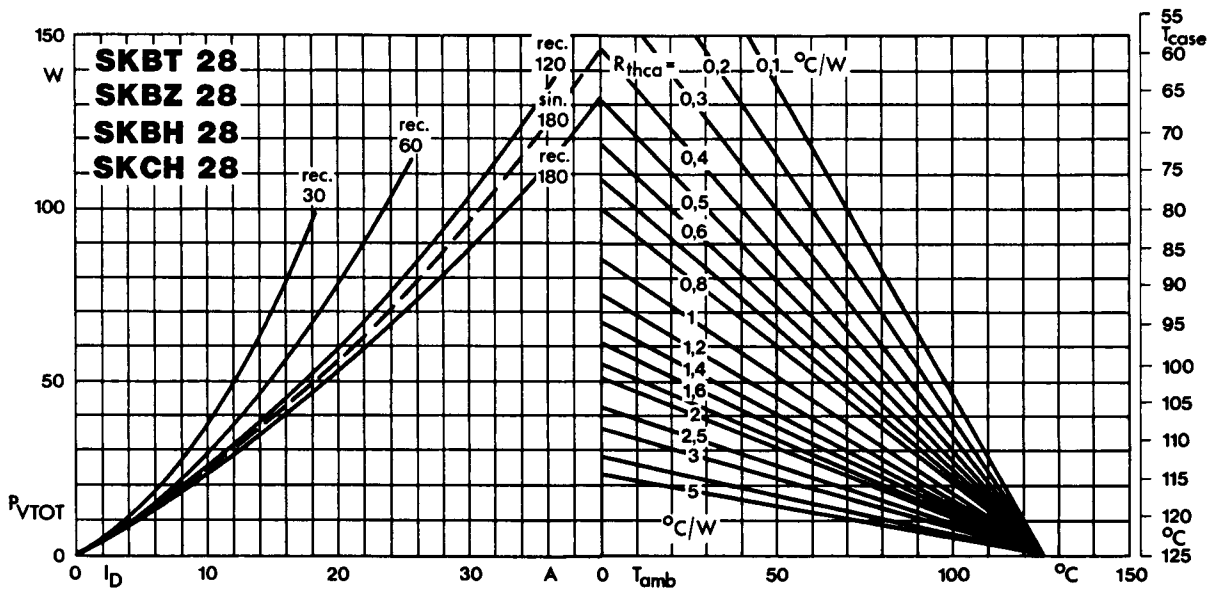


Fig. 4 Power dissipation vs. output current and case temperature

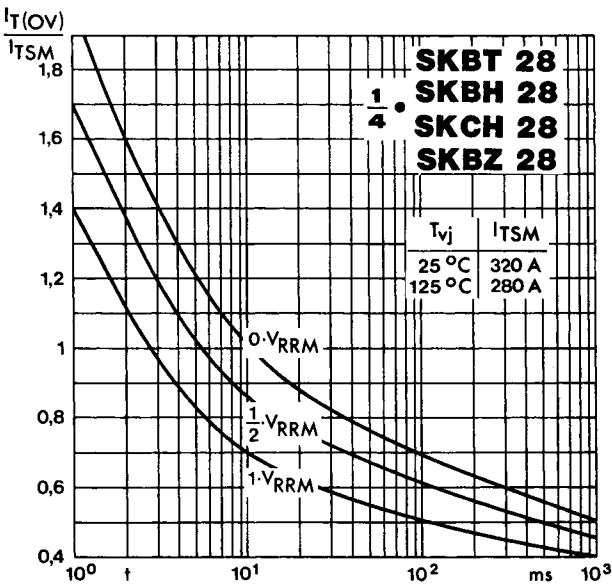


Fig. 5 Surge overload current vs. time

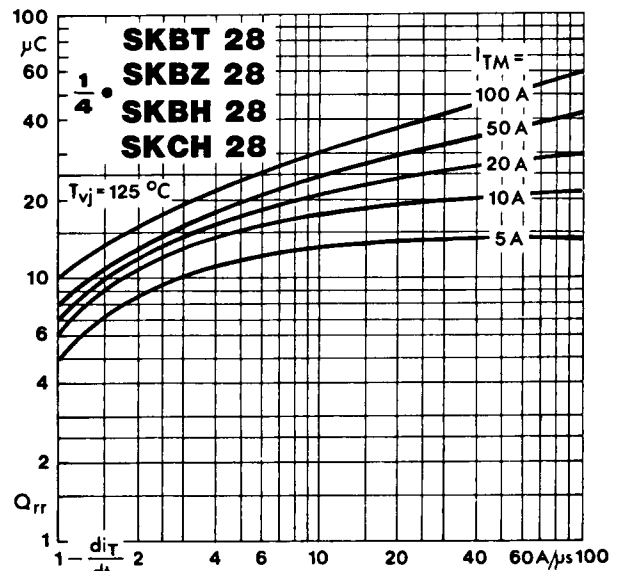


Fig. 8 Recovered charge vs. current decrease

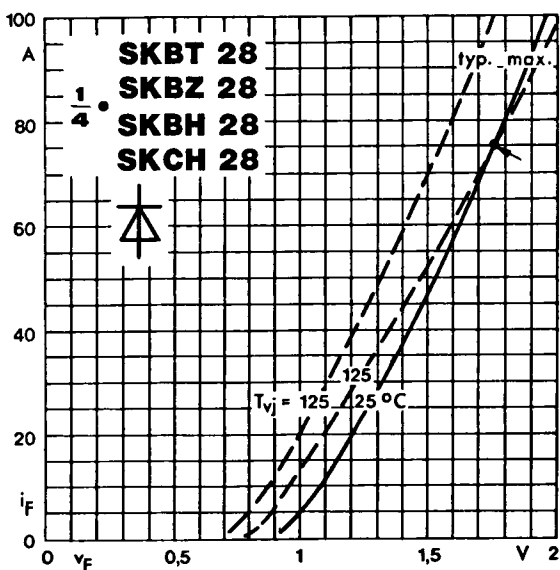


Fig. 9 Forward characteristics of a single diode

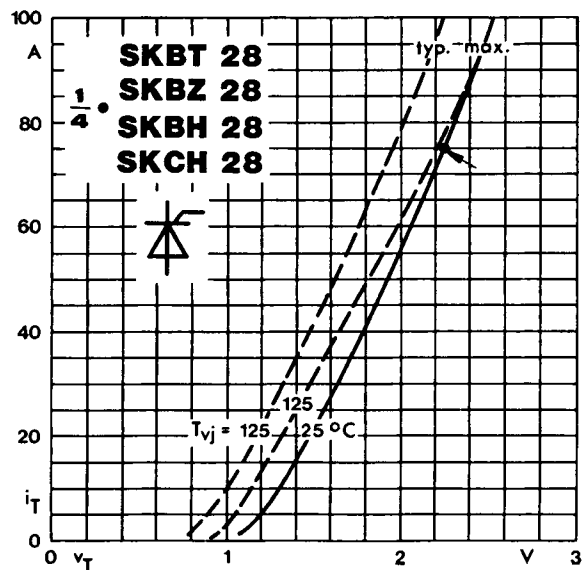


Fig. 10 On-state characteristics of a single thyristor

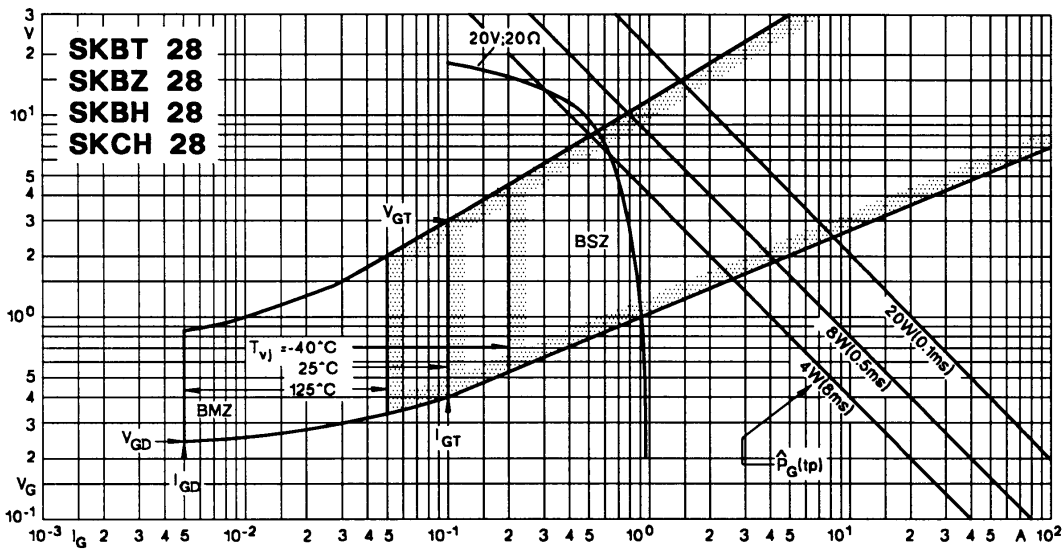


Fig. 11 Gate trigger characteristics

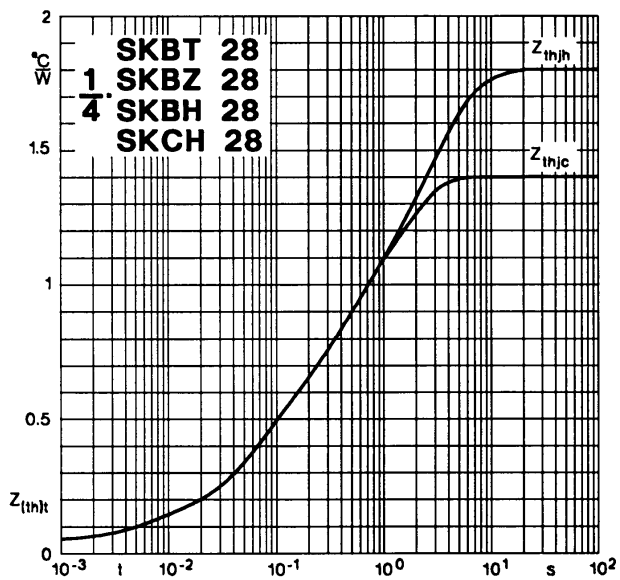
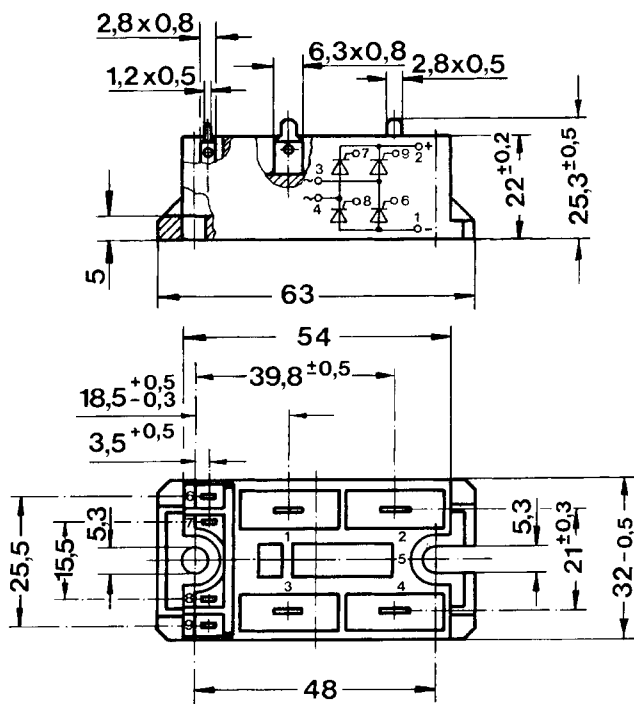
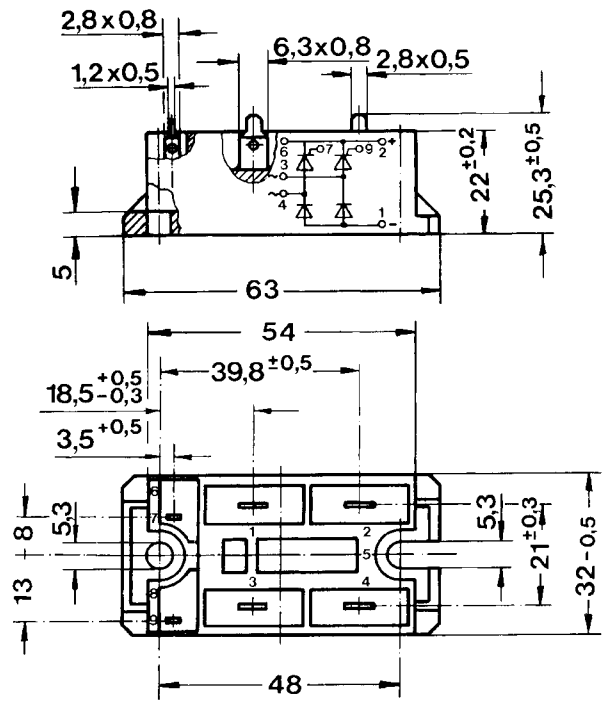


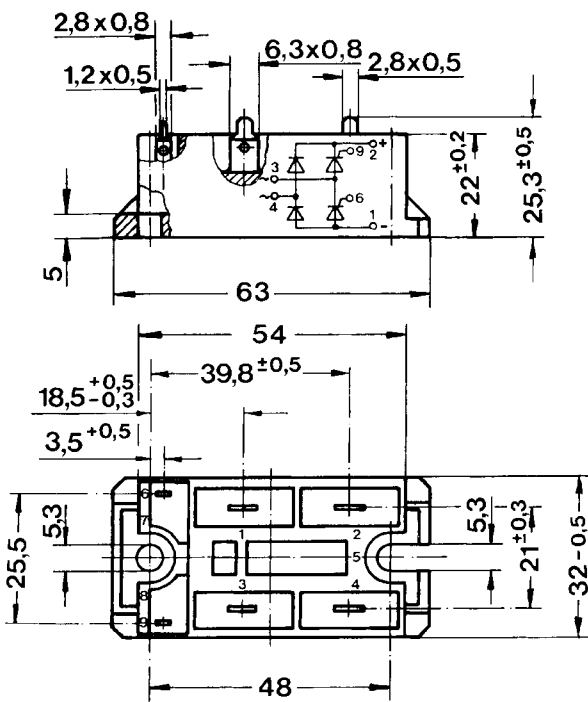
Fig. 12 Transient thermal impedance vs. time

**SKBT 28**Case G 22  
SEMIPONT® 1

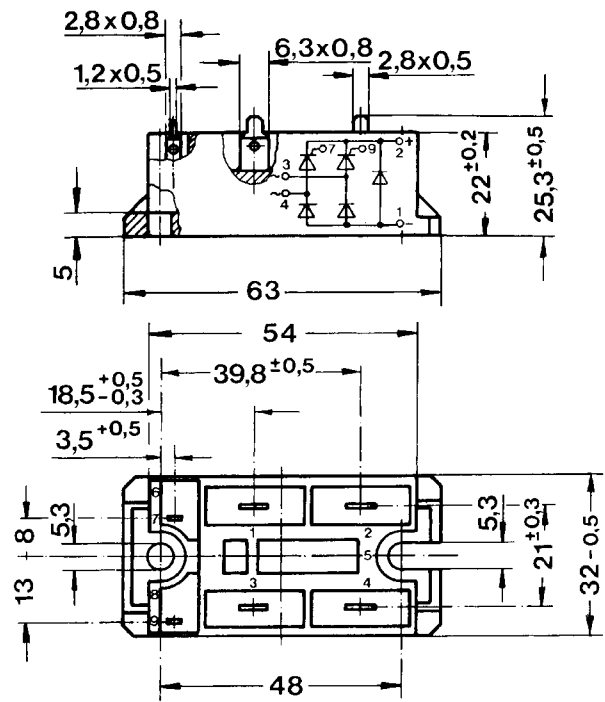
Dimensions in mm

**SKBH 28**Case G 23  
SEMIPONT® 1

Dimensions in mm

**SKBZ 28**Case G 24  
SEMIPONT® 1

Dimensions in mm

**SKCH 28**Case G 25  
SEMIPONT® 1

Dimensions in mm